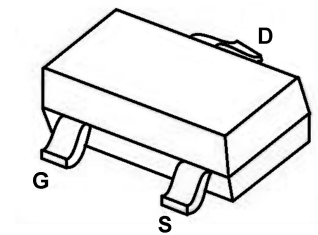


Product Summary

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
-20V	375mΩ@-4.5V	-0.8A
	495mΩ@-2.5V	

Package



SOT 523

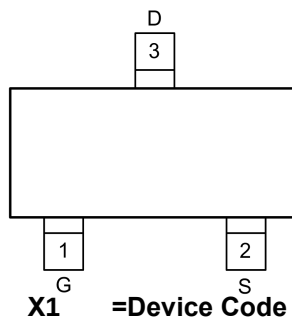
Feature

- Surface Mount Package
- P-Channel Switch with Low $R_{DS(on)}$
- Operated at Low Logic Level Gate Drive
- ESD Protected

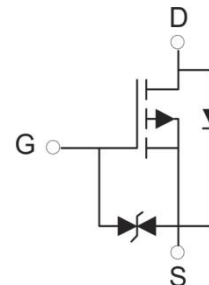
Application

- Load/Power Switching
- Interfacing, Logic Switching
- Battery Management for Ultra Small-Portable Electronics

Marking



Circuit diagram



Absolute maximum ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-20	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current	I_D	-0.8	A
Pulsed Drain Current	I_{DM}	-1.2	A
Power Dissipation	P_D	0.15	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	833	$^{\circ}C/W$
Junction Temperature	T_J	150	$^{\circ}C$
Storage Temperature	T_{STG}	-55~ +150	$^{\circ}C$

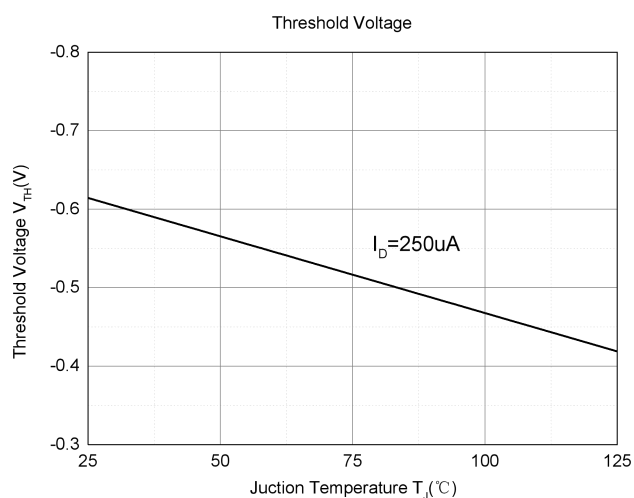
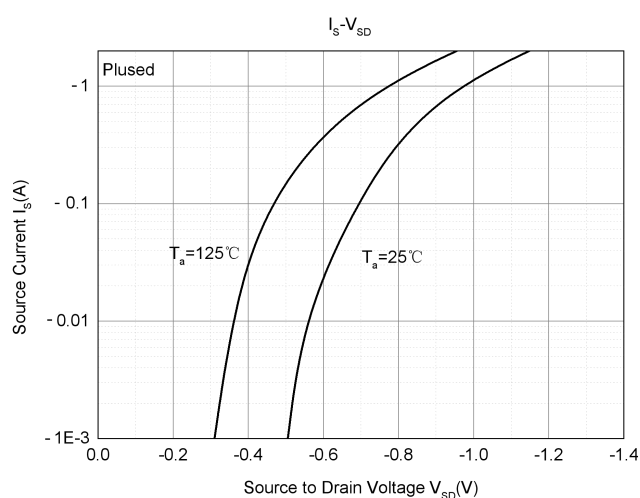
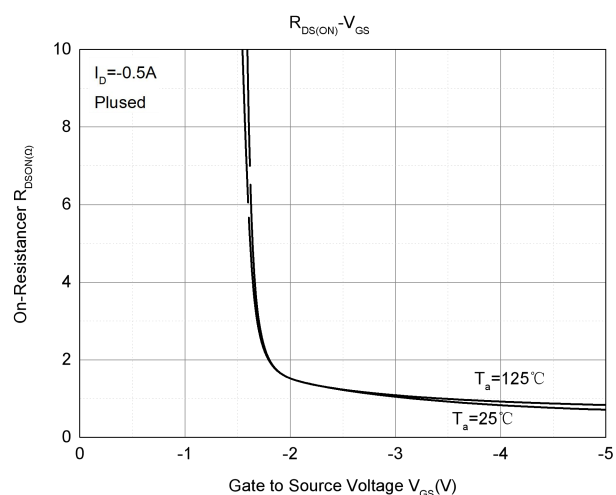
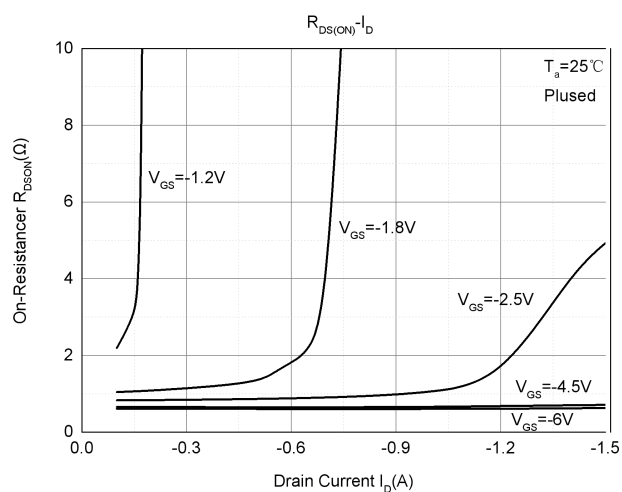
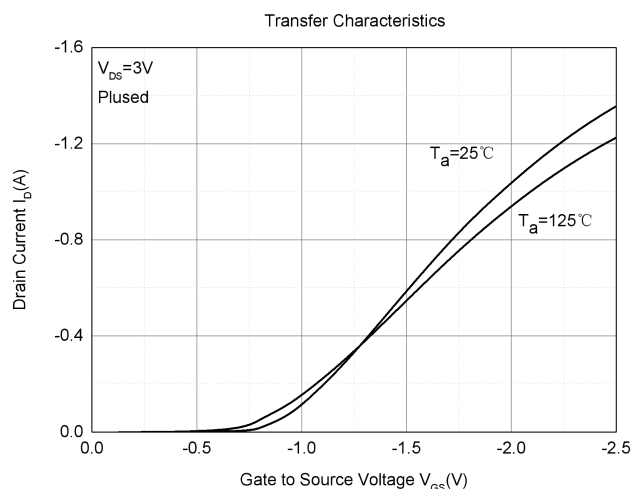
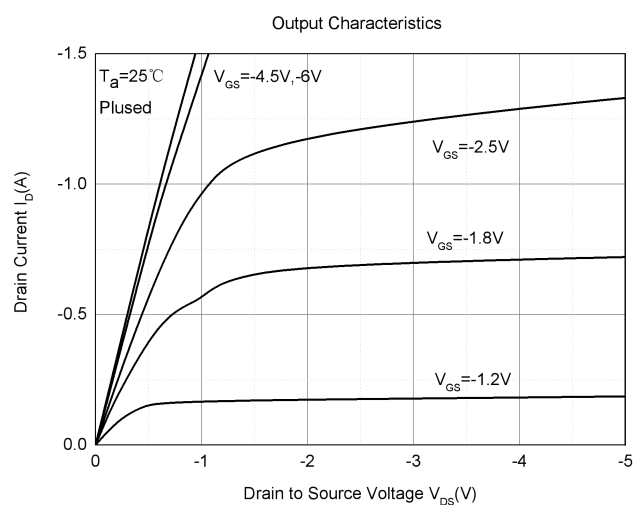
Electrical characteristics (T_A=25 °C, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =-250μA	-20			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =-16V,V _{GS} = 0V			-1	μA
Gate-body leakage current	I _{GSS}	V _{GS} = ±10V, V _{DS} =0V			±10	μA
Gate threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-0.35	-0.65	-1	V
Drain-source on-resistance ¹⁾	R _{DS(on)}	V _{GS} = -4.5V, I _D = -0.8A		290	375	mΩ
		V _{GS} = -2.5V, I _D = -0.6A		380	495	
		V _{GS} = -1.8V, I _D = -0.3A		555		
Dynamic characteristics ²⁾						
Input Capacitance	C _{iss}	V _{DS} =-16V,V _{GS} =0V,f =1MHz		113		pF
Output Capacitance	C _{oss}			15		
Reverse Transfer Capacitance	C _{rss}			9		
Turn-on delay time	t _{d(on)}	V _{DS} =-10V,I _D =-200mA, V _{GS} =-4.5V,R _G =10Ω		9		ns
Turn-on rise time	t _r			5.7		
Turn-off delay time	t _{d(off)}			32.6		
Turn-off fall time	t _f			20.3		
Source-Drain Diode characteristics						
Diode Forward voltage	V _{SD}	V _{GS} =0V, I _S =-0.5 A			-1.2	V

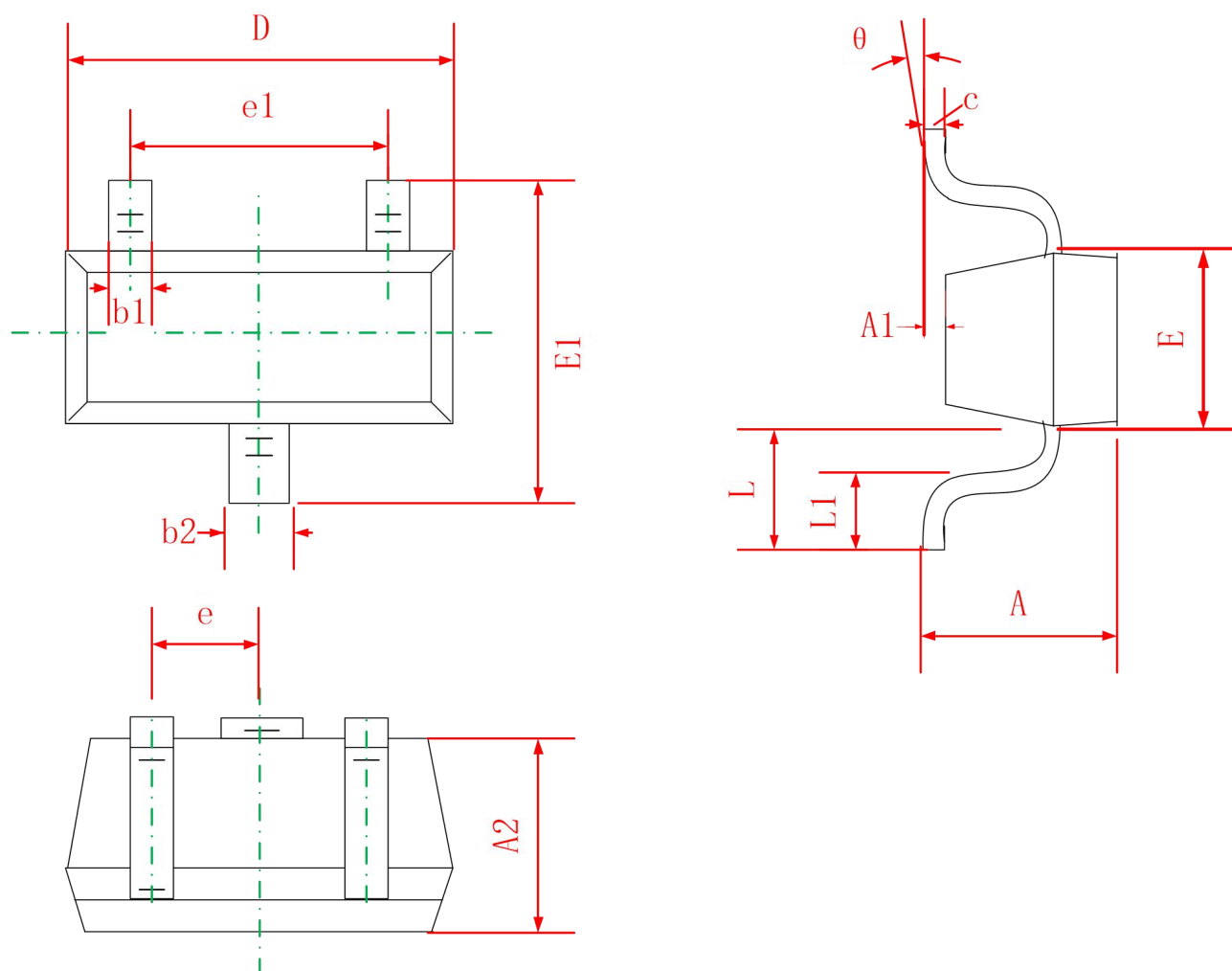
Notes:

- 1) Pulse Test: Pulse Width < 300 μs , Duty Cycle $\leq 2\%$.
- 2) Guaranteed by design, not subject to production testing.

Typical Characteristics



SOT-523 Package Information



Symbol	Dimensions In Millimeters	
	Min	Max
A	0.700	0.900
A1	0.000	0.100
A2	0.700	0.800
b1	0.150	0.250
b2	0.250	0.350
C	0.100	0.200
D	1.500	1.700
E	0.700	0.900
E1	1.450	1.750
e	0.500 TYP	
e1	0.900	1.100
L	0.400 REF	
L1	0.260	0.460
θ	0°	8°